

# Reliability Test Result

Product	MOSFET	Package	Through Hole Devices	Туре	SCT2***, SCH2***
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### 1. Life Test

Test Item	Test Method/ Standard	Test Condition	Sample Size n [pcs]	Failure(s) Pn [pcs]
High Temperature Reverse Bias	$T_a = T_{jmax}$ , $V_{DS} = V_{DSmax} \times 0.8$ JEITA ED-4701/100A-101A	1000 h	22	0
High Temperature Gate Bias	$T_a = T_{jmax}$ , $V_{GS} = V_{GSmax}$ JEITA ED-4701/100A-101A	1000 h	22	0
High Temperature Gate Bias	$T_a = T_{jmax}$ , $V_{GS} = V_{GSmin}$ JEITA ED-4701/100A-101A	1000 h	22	0
Temperature humidity bias	T <sub>a</sub> = 85°C, Rh= 85%, V <sub>DS</sub> = 100V JEITA ED-4701/100A-102A	1000 h	22	0
Temperature cycle	$T_a$ = -55°C (30min) ~ $T_a$ = 150°C (30min) JEITA ED-4701/100A-105A	100 cycles	22	0
Pressure cooker	T <sub>a</sub> = 121°C, 2atm, Rh= 100% JESD22-A102C	48 h	22	0
High Temperature storage	T <sub>a</sub> = 175°C JEITA ED-4701/200A-201A	1000 h	22	0
Low Temperature storage	T <sub>a</sub> = -55°C JEITA ED-4701/200A-202A	1000 h	22	0

### 2. Stress Test

Test Item	Test Method/ Standard	Test Condition	Sample Size n [pcs]	Failure(s) Pn [pcs]
Resistance to solder heat 1	Dipping leads into solder bath at 260±5°C. JEITA ED-4701/301-302A	10 sec	22	0
Resistance to solder heat 2	Dipping leads into solder bath at 350±10°C. JEITA ED-4701/301-302A	3.5 sec	22	0
Solderability	Dipping into solder bath at 245±5°C. JEITA ED-4701/301-303A	5 sec	22	0
Thermal shock	$0^{+5}_{-0}$ (5min) $\sim 100^{0}_{5}$ (5min) JEITA ED-4701/302-307B	100 cycle	22	0
Terminal strength (Pull)	Pull force = 20 N JEITA ED-4701/400A-401A	10 sec	22	0
Terminal strength (Bending)	Bending Load = 10 N JEITA ED-4701/400A-401A	2 times	22	0

- \* Failure criteria: According to the electrical characteristics specified by the specification. Regarding solderability test, failure criteria is 95% or more area covered with solder.
- \*\* Sample standard: [Reliability level:90%] [Failure reliability level(λ1):10%] [C=0 decision] is adopted And the number of samples is being made 22 in accordance with single sampling inspection platwith exponential distribution type based on MIL-STD-19500.

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## 3. Test description

Test description	Test Condition	Failure criteria
1. Soldering heat resistance 1 *3	<ol> <li>Solder: Sn-3Ag-0.5Cu (Lead free)</li> <li><method> <ul> <li>Solder temperature: 260 ±5°C</li> <li>Immerse time: 10 ±1 s</li> <li>Dip the leads once into solder bath. The dipping depth should be up to the stopper. If without stopper, dip up to 1 to 1.5 mm from the body.</li> </ul> </method></li> <li>After dipping, leave at room temperature for more than 2 h.</li> </ol>	<ul> <li>Shall be no mechanical damage.</li> <li>See *1 for failure criterion.</li> </ul>
2. Soldering heat resistance 2 *3	1) Solder: Sn-3Ag-0.5Cu (Lead free) 2) <method> Solder temperature: 350 ±10°C Immerse time: 3.5 ±0.5 s Dip the leads once into solder bath. The dipping depth should be up to the stopper. If without stopper, dip up to 1 to 1.5 mm from the body. 3) After dipping, leave at room temperature for more than 2 h.</method>	<ul> <li>Shall be no mechanical damage.</li> <li>See *1 for failure criterion.</li> </ul>
3. Solderability *3	<ol> <li>Solder: Sn-3Ag-0.5Cu (Lead free)</li> <li>Flux: 2-propanol (IPA) (Rosin 25wt%)</li> <li><method>         Immerse the leads into flux once to the point 1.0 mm from the package body for 10 s, then into solder bath of 245 ±5°C to the point 1.0 mm from the package body for 5 ±0.5 s.         Thereafter, leave at room temperature. Then wash off flux in 2-propanol.     </method></li> </ol>	•At least 95% of immersed surface must be covered by solder, which is confirmed through 10~20X magnifying glass.
4. Heat shock	1) <temperature &="" time=""> 95~100°C ⇔ 0~5°C (Liquid) 5 min (Liquid) 5 min Change within 10 s.  2) Repeat prescribed cycles.  3) After completion of test, leave at room temperature for more than 2 h.</temperature>	•See *1 for failure criterion.
5. Temperature cycle	Temperature & Time>     -55°C ⇔ 150°C     (Air) 30 min (Air) 30 min  Repeat prescribed cycles.  After completion of test, leave at room temperature for more than 2 h.	•See *1 for failure criterion.
6. Temperature humidity bias	<ol> <li>T<sub>a</sub>= 85±3°C         RH= 75~90%</li> <li>V= 100V</li> <li>After completion of test, leave at room temperature for more than 2 h.</li> </ol>	•See *1 for failure criterion.

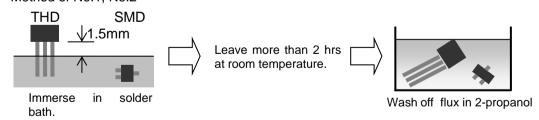
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7. Pressure cooker test	<ol> <li>T<sub>a</sub>=121°C, 100%RH</li> <li>P=203kPa [2 atm]</li> <li>After completion of test, leave at room temperature for more than 2 h.</li> </ol>	•See *1 for failure criterion.
8. High temperature reverse bias	<ol> <li>T<sub>a</sub>=T<sub>j(max)</sub> ±2°C</li> <li>V=SPECIFIED VOLTAGE</li> <li>After completion of test, leave at room temperature for more than 2 h.</li> </ol>	<ul> <li>Shall be no mechanical damage.</li> <li>See *1 for failure criterion.</li> </ul>
9. High temperature gate bias *3	<ol> <li>T<sub>a</sub>=T<sub>j(max)</sub>±2°C</li> <li>V<sub>GS</sub>=Maximum Rating</li> <li>After completion of test, leave at room temperature for more than 2 h.</li> </ol>	<ul><li>Shall be no mechanical damage.</li><li>See *1 for failure criterion.</li></ul>
10. High temperature storage	<ol> <li>T<sub>a</sub>= T<sub>stg(max)</sub></li> <li>After completion of test, leave at room temperature for more than 2 h.</li> </ol>	<ul><li>Shall be no mechanical damage.</li><li>See *1 for failure criterion.</li></ul>
11. Low temperature storage	<ol> <li>T<sub>a</sub>= T<sub>stg(min)</sub></li> <li>After completion of test, leave at room temperature for more than 2 h.</li> </ol>	<ul><li>Shall be no mechanical damage.</li><li>See *1 for failure criterion.</li></ul>
12. Lead strength (Lead bend)	<ol> <li>(All the sample body, and bend the terminal to 90° twice loading specified force.</li> </ol>	•Shall be no mechanical damage, detachment, extention between the lead and the package body
13. Lead strength (Lead pull)	<ol> <li>Amethod     Fix the sample body and keep pulling the lead in lead axis direction with specified load for 10 ±1 s.</li> </ol>	•Shall be no mechanical damage, detachment, extention between the lead and the package body

### 4. Remark

\*1 Failure criterion : According to the electrical characteristics specified by the specification

### \*2 Method of No.1, No.2



### \*3 Preconditioning

Perform aging with the pressure cooker equipment. (105°C, 100%, 1.22 $\times$ 10<sup>5</sup> Pa, 4 h)

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